

IBAAS 2025
TECHNICAL LECTURE SERIES

**4N HPA: SCIENCE, STRATEGY,
AND SCALE – A MATERIAL AT THE
CROSSROADS OF INNOVATION**



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- ❑ Introduction & Objective
- ❑ High Purity Alumina (4N HPA)
- ❑ Why Purity Matters
- ❑ HPA Forms and their Uses
- ❑ Global Demand and Its Applications
- ❑ Current HPA Production Technologies
- ❑ Industrial Value Chain & Market Landscape
- ❑ Key Players & Cost Benchmarks
- ❑ Work Done on HPA at JNARDDC
- ❑ From Lab Success to Bench-Scale Reality
- ❑ Key Takeaways and The Road Ahead

Introduction & Objective

Introduction

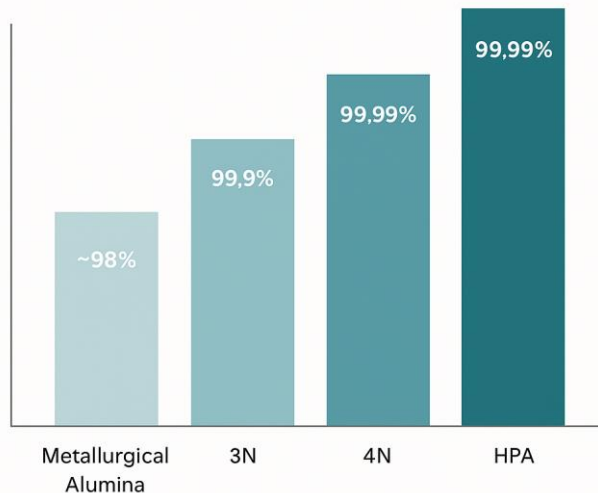
- **High Purity Alumina (4N, 99.99%)**
- **Chemical Stability, Optical transparency, high thermal resistance**
- **LED Phosphors, Lithium-Ion Batteries, Semiconductor substrates**

Objectives

- **To introduce the science behind 4N HPA, its key properties and applications.**
- **To highlight the strategic and economic importance of developing domestic capability.**
- **To explore how investors and industry can leverage emerging opportunities.**
- **To present R&D efforts and breakthroughs achieved at JNARDDC, including a lab-scale validated process for producing 4N HPA.**

High Purity Alumina (4N HPA)

What is High Purity Alumina (HPA)?



Grade

Typical Use

3N (99.9%)

Ceramics, Phosphors

4N (99.99%)

LED, Sapphire Glass

5N (99.999%)

Semiconductors, Optics

PERIODIC TABLE OF THE ELEMENTS

1	PERIODIC TABLE OF THE ELEMENTS																5	6														
2	H 124	2																8	7	8	9	10	11									
3	Li 223	Be 257																	B 53	C 88	N 85	O 42	F 51	Ne 236								
4	Na 63	Mg 66	3			4	5	6	7	8	9	10	11	12	Al 62	Si 102	P 106	S 113	Cl 118	Ar 159												
5	K 129	Ca 149	Sc 140	Ti 189	V 142	Cr 109	Mn 189	Fe 182	Co 109	Ni 131	Cu 183	Zn 105	Ga 197	Ge 193	As 169	Se 186	Br 173	Kr 201														
6	Rb 91	Sr 42	Sr 59	Zr 97	37	Mo 194	Tc 196	Ru 209	Rh 201	Pd 202	Ag 239	Cd 244	In 236	Sn 296	Sb 209	Te 296	I 234	Xe 279														
7	Cs 163	Ba 502	La 504	Hf 516	31	W 572	Re 539	Os 153	Ir 538	Pt 564	Au 509	Hg 361	Tl 591	Pb 576	Bi 774	Po 768	At 713	Rn 300														
8	Fr 101	Ra 108	Ac 107	Rf 108	Db 111	Sg 118	Bh 118	Hs 132	Mt 196	Ds 199	Rg 102	Cn 143	Nh 153	Fl 158	Mc 162	Lv 154	Ts 154	Og 185														
Lanthans																				La 34	Ce 35	Pr 36	Nd 37	Sm 58	Eu 59	Gd 60	Tb 41	Dy 42	Ho 43	Er 44	Tm 45	Lu 46
Actines																				Ac 37	Th 48	Pa 49	U 50	Np 51	Am 52	Cm 53	Bk 54	Cf 55	Es 56	Fm 57	Md 58	No 59

Why Purity Matters ?

Achieving high purity ensures that the following properties are maximized, allowing HPA to perform optimally in demanding applications:

- ☐ **High melting point: $\sim 2050^{\circ}\text{C}$ – suitable for extreme environments**
- ☐ **Excellent hardness and chemical stability**
- ☐ **High dielectric strength and thermal conductivity**
- ☐ **Transparent to visible and infrared light (especially sapphire form)**
- ☐ **Inert and non-reactive nature**

The form and purity of HPA determine its application and market value

HPA Forms and Functional Use

Powdered HPA



Used in ceramics,
battery separators,
and phosphors

Granular HPA



For sintered
components and
crucibles

Sapphire form (single crystal Al_2O_3)



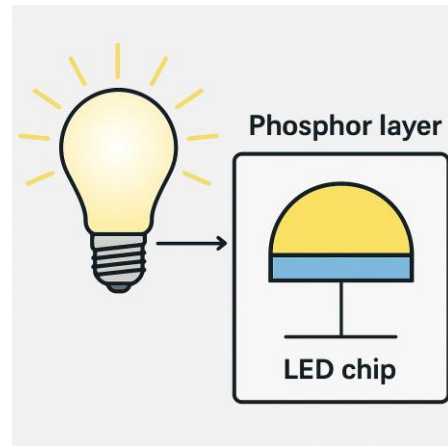
Used in LED
substrates, watch
crystals, and
optical windows

Global Demand and Its Applications

HPA use in LED Phosphors

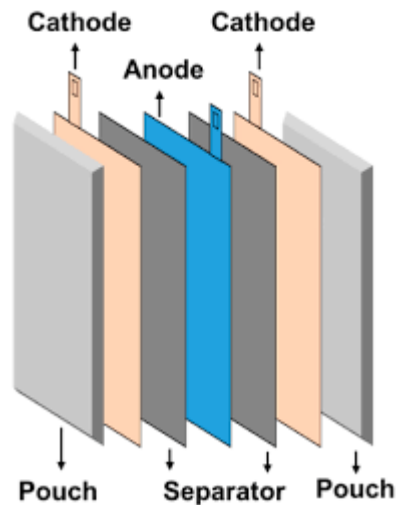
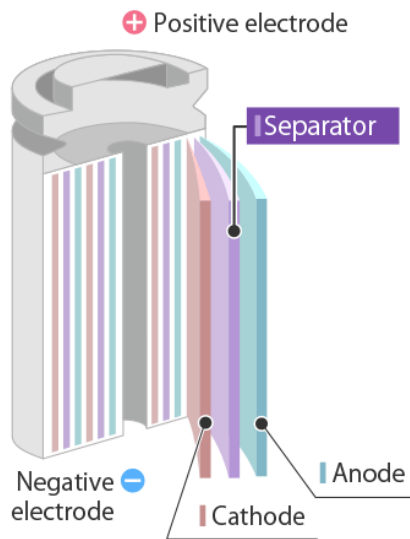
4N HPA in LED Phosphors:

- **Application:** High-purity alumina (HPA) is used as a key component in the production of LED phosphors.
- **Role:** Enhances brightness and color efficiency in LED lights, making them more energy-efficient and long-lasting.
- **Market Demand:** As the LED industry grows due to energy-saving initiatives and lighting upgrades, the demand for HPA in this sector is expected to increase.



HPA for Lithium Ion Batteries Separator

- **Application:** HPA is utilized in the production of separators for lithium-ion batteries, which are critical in electric vehicles (EVs) and portable electronic devices.
- **Role:** Provides high thermal stability, mechanical strength, and chemical resistance, improving battery life and safety.
- **Market Demand:** With the rise of electric vehicles and portable electronics, the demand for advanced battery technologies and separators is growing, driving the need for HPA.



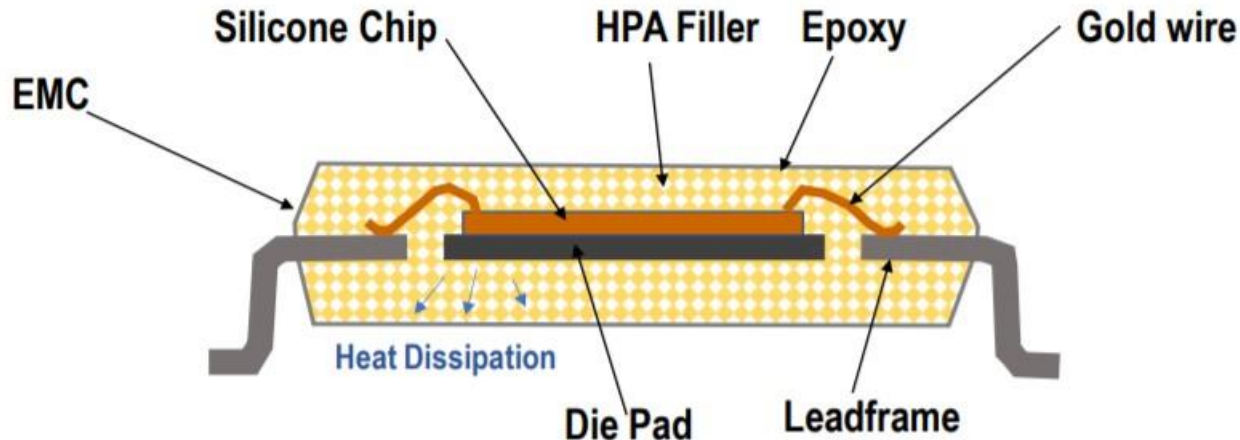
HPA for Sapphire Substrates

- **Application:** HPA is used to produce high-quality sapphire substrates for use in semiconductor and optical applications.
- **Role:** Provides a stable, high-quality substrate that is essential for the production of blue and white LEDs, as well as for use in advanced electronic devices.
- **Market Demand:** The continued advancement of the electronics and LED industries, alongside emerging applications in photonics, is driving the demand for sapphire substrates.



HPA for Semiconductor and Optical Applications

- **Application:** HPA is used in the manufacturing of semiconductor devices and optical components, including lenses and windows for high-performance lasers.
- **Role:** Offers excellent purity, high thermal stability, and optical transparency, making it essential for next-generation electronic and optical devices.
- **Market Demand:** With the increasing demand for high-performance semiconductors in data centers, telecommunications, and emerging technologies like quantum computing, the need for HPA in these sectors is expected to grow.





Current HPA Production Technologies

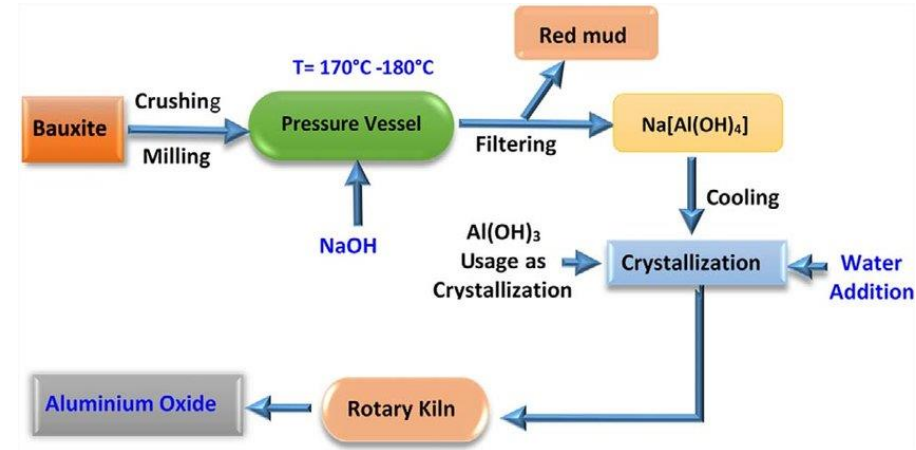
Bayer's Process: Traditional Alumina Route

Pros:

- **Mature Technology:** Well-established process with a global presence.
- **High Yield:** Efficient at producing alumina from bauxite.
- **Scalable:** Suitable for large-scale industrial production.

Cons:

- **Energy-Intensive:** Requires significant energy for calcination.
- **Environmental Impact:** Large amounts of red mud (waste byproduct) are generated.
- **Limitations for HPA:** Not directly suited for high-purity alumina, additional purification steps are needed.



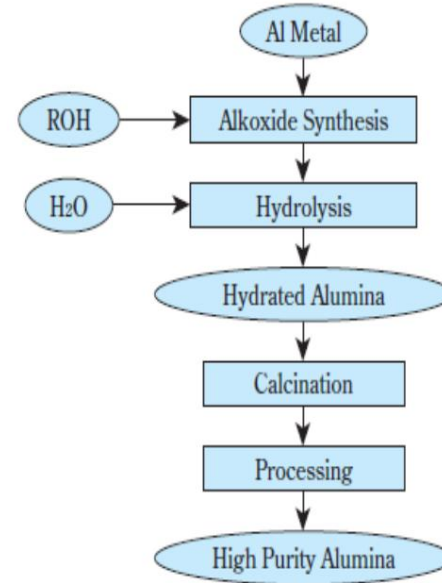
Alkoxide Process

Pros:

- **High Purity:** Direct production of HPA with minimal impurities.
- **Control over Purity:** Allows precise control over the purity level of alumina.
- **Suitability for Specialty Applications:** Ideal for producing ultra-high purity materials used in LEDs and semiconductors.

Cons:

- **High Cost:** Requires expensive chemicals and energy for the reaction.
- **Scale-Up Challenges:** Less proven at industrial scale compared to Bayer process.
- **Complex Process:** Involves multiple steps requiring precise control.



Hydrothermal and Hydrochloric Acid Leaching

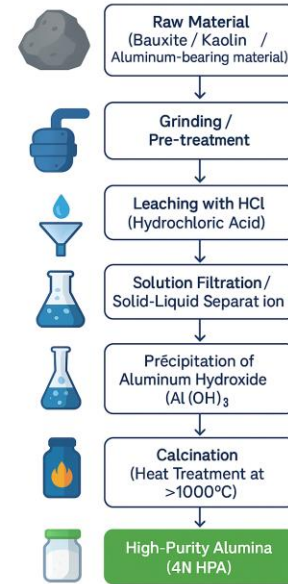
Pros:

- **Efficient Extraction:** Effective for processing a variety of raw materials, including low-grade ores.
- **Flexible:** Can use alternative raw materials, not just bauxite.
- **Low Energy Consumption:** Potential for lower energy consumption compared to Bayer process.

Cons:

- **Complexity in Purification:** Requires additional purification steps to achieve high purity.
- **Corrosive Chemicals:** Use of hydrochloric acid can lead to equipment corrosion and environmental concerns.
- **Scalability Issues:** Less established for large-scale commercial production.

Hydrothermal / HCl Leaching Process for HPA Production

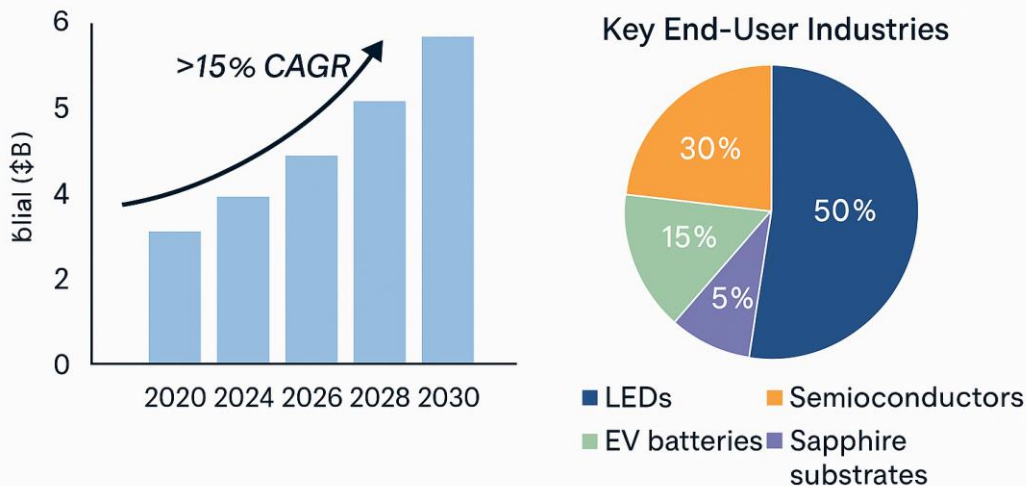




Industrial Value Chain & Market Landscape

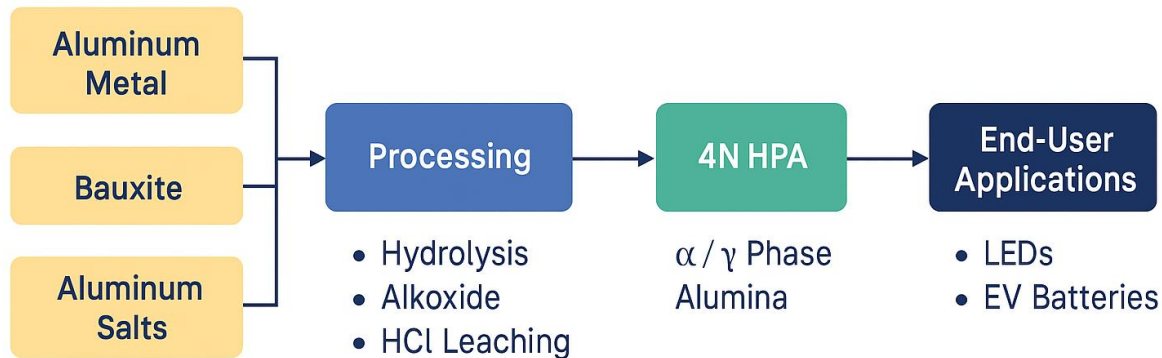
Global 4N+ HPA Market Landscape

Emerging Demand & Market Projections



The global market for High Purity Alumina was valued at US\$17.3 Billion in 2024 and is projected to reach US\$52.6 Billion by 2030, growing at a CAGR of 20.3% from 2024 to 2030.

HPA Value Chain



Investment Opportunities & Challenges

Strengths

- High margin market
- Government initiatives and PLI schemes
- Rising domestic consumption

S

Weaknesses

- Access to technology
- Impurity control
- Capital intensity

W

Opportunities **O**

- Import substitution goals
- Atmanirbhar Bharat mission
- Public/private partnerships

T Threats

- Competition from China, Australia, Japan
- High production costs
- Environmental concerns

Key Players & Cost Benchmarks

Global Market Dynamics: Players, Costs & Competitive Edge

Major Global Players:

- Altech Chemicals (Australia)
- Sasol (South Africa)
- Sumitomo Chemicals (Japan)
- Orbite Technologies (Canada)

Typical Production Routes:

- Hydrochloric Acid Leaching
- Alkoxide Process
- Thermal decomposition of Aluminium Salts

Cost Benchmarking (for 4N HPA):

- Global Average Cost - \$ 14-20/Kg
- Indian R&D based Cost- ₹ 500-600/kg (approx. \$ 6-7 excluding manpower and scale-up factors)



Work Done on HPA at JNARDDC- Project Overview

Project Details

Title: Development of Process for 4N High Pure Alumina (HPA) and Substrate Making for its Validation in LED Applications

OBJECTIVES



Develop a process know-how for 4N HPA preparation



Preparation of sapphire



Validation of sapphire for LEDs



Cost Economics for developed process



JNARDDC, Nagpur

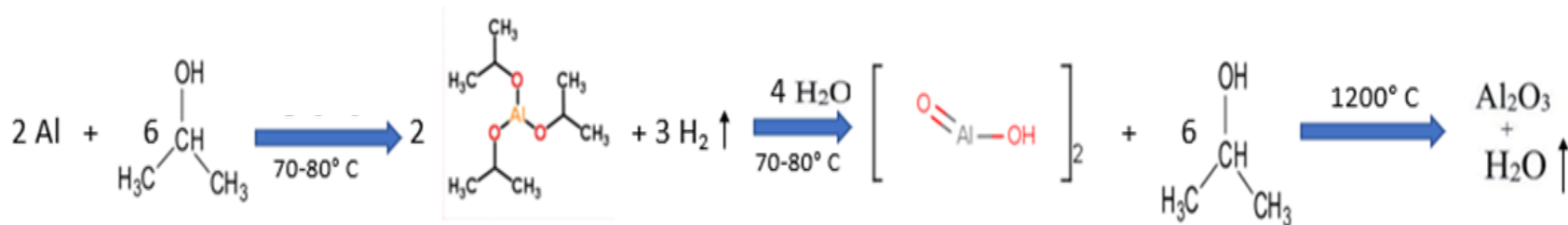
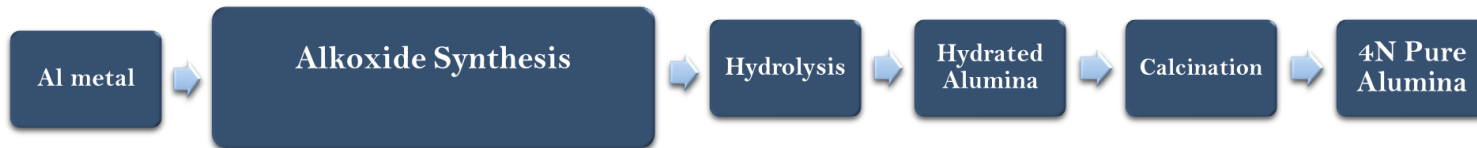


IIT Bhubaneswar



Anna University

Process Methodology – Alkoxide Route Using Aluminum Metal



Advantages of Alkoxide Hydrolysis Method

Fast reaction speed,

High purity of the product,

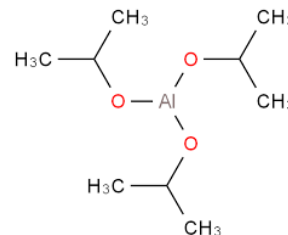
Isopropyl Alcohol recycling,

And Reuse

Precursor Advantage: Role of AIP in HPA Purity

- **Precursor Purity:** AIP can be synthesized with high purity and if used as a precursor, initial purity carries through to the final product i.e HPA.
- **Controlled Reaction Pathways:** Precise manipulation of reaction conditions
- **Reduced contaminant introduction:** With its well defined chemical structure, introduction of unwanted contaminants can be reduced
- **Fewer Purification steps:** Highly pure precursor reduce the need for extensive purification steps means less potential for contamination
- **Tailored Synthesis routes:** AIP provides flexibility in defining synthesis routes
- **Optimized Reaction Conditions:** Temperature and Pressure optimization leads to more efficient reaction with fewer unwanted products

The central Aluminium is octahedral surrounded by three bidentate (O--Pr)₄ ligands, each featuring tetrahedral Al.



Unique chemical structure of AIP

Catalyst-free Approach: Cleaner, Safer Pathway

Why It Matters:

Traditional synthesis methods for HPA often rely on toxic catalysts like **iodine** and **mercury chloride**, posing safety, environmental, and regulatory challenges.

Our Breakthrough:

JNARDDC's catalyst-free route eliminates hazardous chemicals while maintaining ultra-high purity.

- **Controlled temperature for precise reaction kinetics**
- **Regulated pressure to maintain reaction equilibrium**
- **Optimized reaction time for purity + efficiency**

Advantages Over-Catalyst Based Methods

Catalyst-Based (Iodine, HgCl ₂)	Catalyst-Free (JNARDDC)
Uses Toxic and hazardous substances	Environmentally Benign
Requires additional removal steps	Simplified Process
Risk of catalyst contamination in final product	Cleaner, higher purity
Higher cost due to catalyst handling and disposal	Lower operational cost
Regulatory challenges for toxic chemicals	Safer, scalable, compliant

How Pure Are Our Raw Materials?

Purity analysis of aluminium metal received from NALCO

Elements	Iron (Fe) Wt %	Silicon (Si) Wt %	Copper (Cu) Wt %	Manganese (Mn) Wt %	Zinc (Zn) Wt %	Vanadium (V) Wt %	Gallium (Ga) Wt %	Titanium (Ti) Wt %	Magnesium (Mg) Wt %	Chromium (Cr) Wt %	Nickel (Ni) wt %	Barium (Ba) wt %	Calcium (Ca) wt %	Sodium (Na) wt %	Strontium (Sr) wt %	Total Purity
NALCO	0.061	0.018	0.007	0.002	0.003	0.003	0.007	0.004	0.002	0.001	0.004	0.001	0.001	0.006	0.001	99.878 %
JNARDDC	0.040	0.025	0.0003	0.0007	0.0018	0.0030	0.0075	0.005	0.0007	0.0007	0.0008	0.0011	0.0002	0.005	ND	99.905 %

Purity analysis of Iso Propyl Alcohol

Water	Fe	Ti	Ca	V	P	Ga	Mg	Si
0.01%	0.093 ppm	ND	0.036 ppm	ND	0.031 ppm	ND	ND	ND

Intermediate and Final Purity Milestones

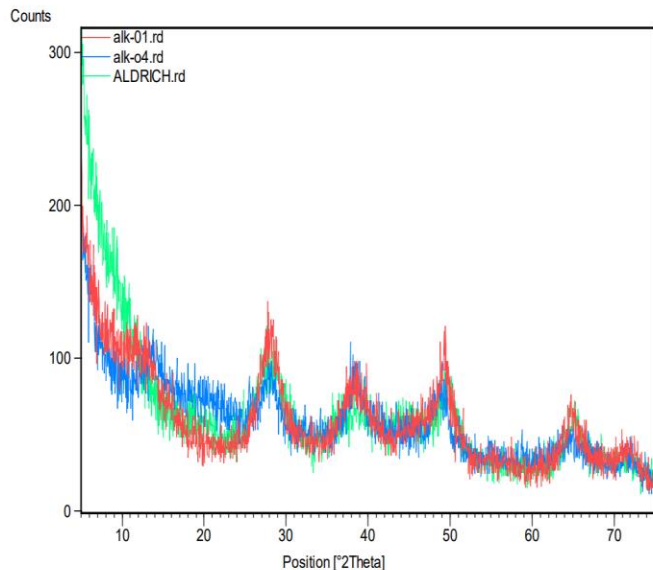
ICP-Analysis of Intermediate Products

Elements %	Fe ₂ O ₃	SiO ₂	Cu ₂ O ₃	Mn ₂ O ₃	Mg ₂ O ₃	Zn ₂ O ₃	TiO ₂	V ₂ O ₅	P ₂ O ₅	CaO	Purity
AIP	0.0404	0.0246	0.00044	0.00023	0.00081	0.00199	0.0049	0.00030	0.00119	0.0076	99.9053
Al Hydrate	0.037	0.0223	0.00023	0.00021	0.00092	0.00174	0.0051	0.00035	0.00328	0.00054	99.90921

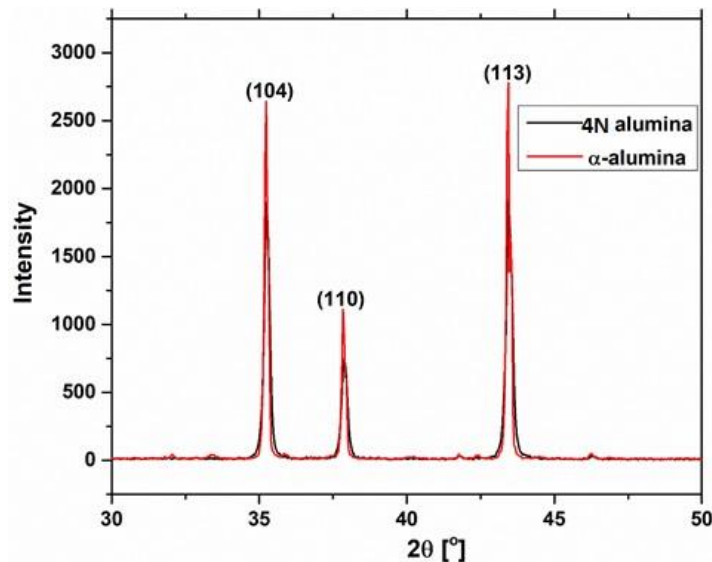
ICP-Analysis of final Product

Sample ID	SiO ₂ (%)	TiO ₂ (%)	Fe ₂ O ₃ (%)	CaO (%)	P ₂ O ₅ (%)	V ₂ O ₅ (%)	Al ₂ O ₃ (%)
ALK-52	0.0023	0.001	0.007	0	0.0003	0.0004	99.989
Al ₂ O ₃ Sigma Aldrich	0.0011	0.001	0.007	0	0	0.0019	99.989

Crystallographic Match: Synthesized vs Standard Materials

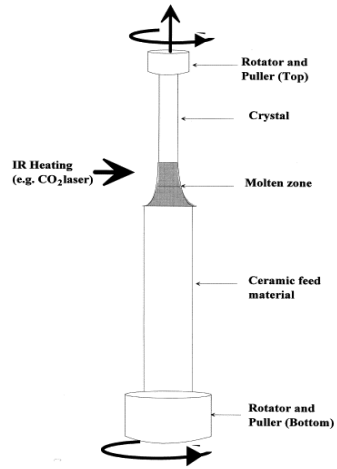


**Comparative diffractogram of prepared AIP
with the one procured commercially**



**Comparative Diffractogram of prepared HPA
with the commercially procured**

From HPA to Sapphire



**Schematic of Float zone
method**



**Sapphire Growth facility
installed at Anna University**

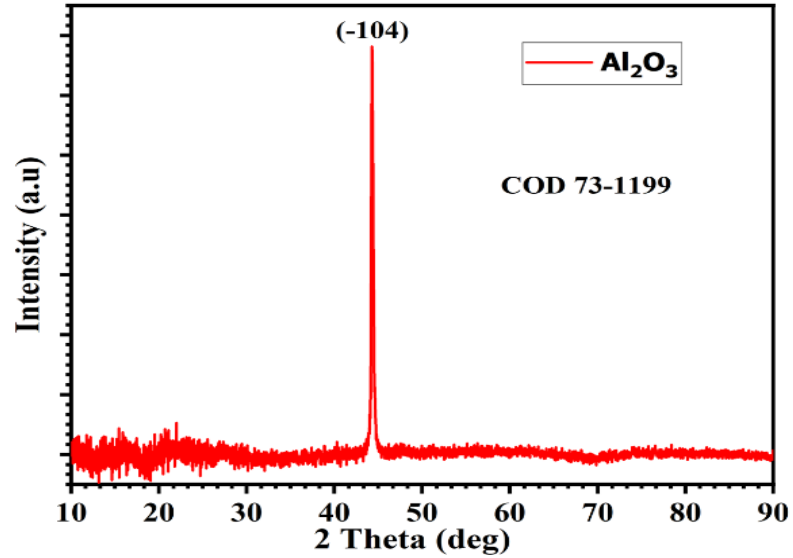


**Float Zone growing
the crystal from melt**

Single crystal →
grown (5 cm x 1cm)



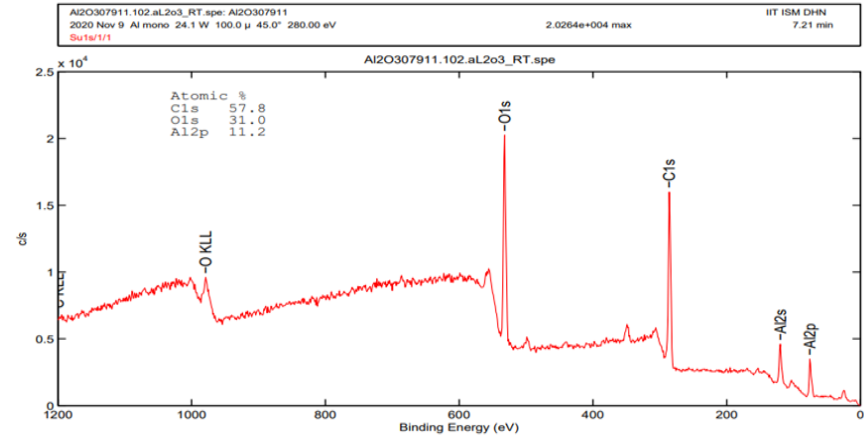
Structural and Surface Purity of Sapphire



↑

HRXRD

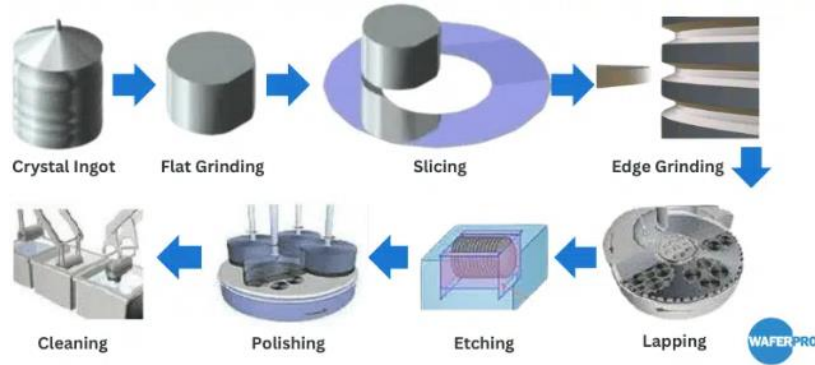
XPS



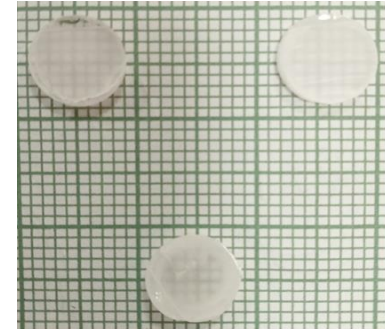
Alumina Wafer Fabrication



Single crystal grown



Wafer Manufacturing Process



Al_2O_3 wafers (Dia.10 mm and thickness 1.5 mm)

Functional Characterization of Alumina Wafers



1 kgf

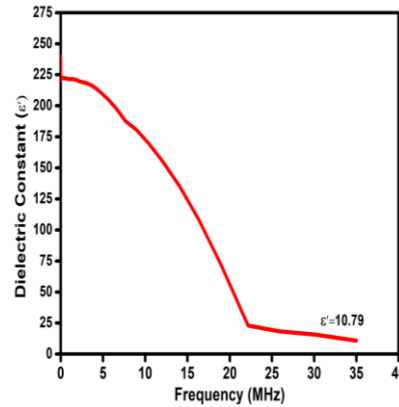
76.56 GPa

0.5 kgf

31.72 GPa

Vicker's Hardness:

$$HV = \frac{2F \sin \frac{\alpha}{2}}{gd^2}$$



$$\epsilon_r = \frac{Cp d}{\epsilon_o A}$$

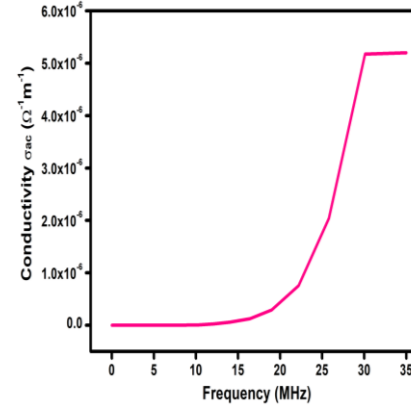
$$\epsilon_r = 9.5 \text{ at } 1 \text{ MHz}$$

C_p = Capacitance

d = thickness of the sample

A = area of the sample

ϵ_o = Absolute permittivity of free space ($8.854 \times 10^{-12} \text{ C}^2\text{N}^{-1} \text{ m}^{-2}$)



$$\sigma_{ac} = \epsilon_o \epsilon_r \omega \tan \delta$$

$$\sigma_{ac} = 5.2 \times 10^{-7} \Omega^{-1} \text{ m}^{-1}$$

ϵ_o = absolute permittivity

ϵ_r = Dielectric constant

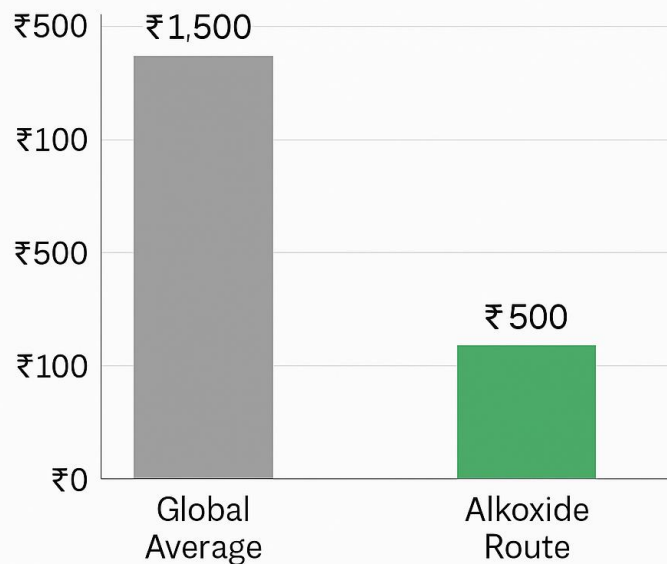
$\omega = 2\pi f$

$\tan \delta$ = Dielectric loss

Dielectric Properties

Cost Advantage of Alkoxide Route

**Cost of 4N HPA Production –
Global vs Alkoxide Route**



**Cost-Efficient Pathway to
4N HPA via Alkoxide Route**



From Lab Success to Bench-Scale Reality

- Scale-up of Alkoxide Based HPA Process
- Design and Set up of Bench-Scale Reactor System
- Optimization of Process Parameters
- Material Characterization at Larger Scale
- Evaluation of End-Use Suitability
- Proposal for Funding and Industry Partnership

Key Takeaways and The Road Ahead

- **4N High Purity Alumina is a strategic material**
Critical for advanced applications like LEDs, semiconductors, and sapphire substrates
- **Growing global demand presents investment opportunities**
Especially for India to emerge as a self-reliant supplier.
- **Lab-scale success at JNARDDC validates the potential**
Alkoxide-based HPA process offers promise for scale-up
- **Next phase: Bench-scale production & industry partnerships**
Aimed at commercialization, cost-efficiency, and application testing
- **Collaboration is key**
Investors, industry partners, and R&D institutes can jointly unlock value

Thank You!

For your time and attention

For Collaboration & Queries:

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Let's connect and innovate together.